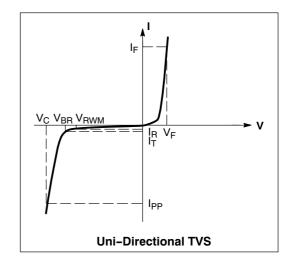
μESD3.3ST5G SERIES

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted)

	<u> </u>				
Symbol	Parameter				
I _{PP}	Maximum Reverse Peak Pulse Current				
V _C	Clamping Voltage @ IPP				
V_{RWM}	Working Peak Reverse Voltage				
I _R	Maximum Reverse Leakage Current @ V _{RWM}				
V_{BR}	Breakdown Voltage @ I _T				
Ι _Τ	Test Current				
I _F	Forward Current				
V_{F}	Forward Voltage @ I _F				
P _{pk}	Peak Power Dissipation				
С	C Max. Capacitance @V _R = 0 and f = 1 MHz				



ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted, $V_F = 1.1$ V Max. @ $I_F = 10$ mA for all types)

	Device	V _{RWM} (V)	I _R (μΑ) @ V _{RWM}	V _{BR} (V) @ I _T (Note 2)	I _T	V _C (V) @ Max I _{PP} †	I _{PP} (A) [†]	P _{pk} (W) [†]	C (pF)
Device*	Marking	Max	Max	Min	mA	Max	Max	Max	Тур
μESD3.3ST5G	E0	3.3	2.5	5.0	1.0	10.9	10.4	113	80
μESD5.0ST5G	E2	5.0	1.0	6.2	1.0	13.3	8.8	117	65
μESD12ST5G	E3	12	1.0	13.5	1.0	23.7	5.4	128	30

^{*}Other voltages available upon request.

[†]Surge current waveform per Figure 1.
2. V_{BR} is measured with a pulse test current I_T at an ambient temperature of 25°C.

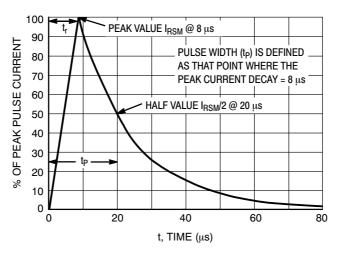


Figure 1. 8 x 20 µs Pulse Waveform

μESD3.3ST5G SERIES

TYPICAL CHARACTERISTICS

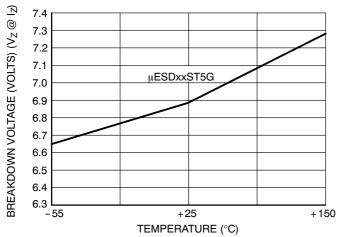


Figure 2. Typical Breakdown Voltage versus Temperature

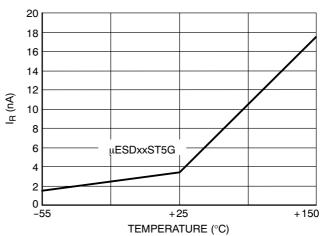


Figure 3. Typical Leakage Current versus Temperature

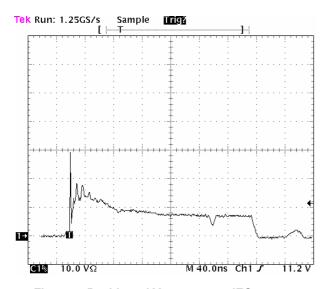


Figure 4. Positive 8 kV contact per IEC 6100-4-2 - μESD5.0ST5G

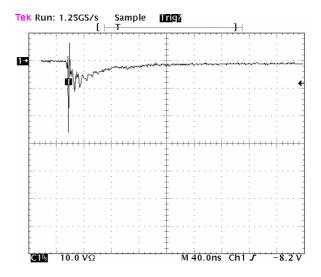
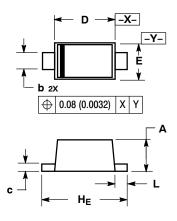


Figure 5. Negative 8 kV contact per IEC 61000-4-2 $- \mu$ ESD5.0ST5G

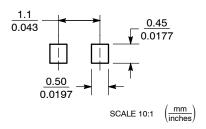


SOD-723 CASE 509AA-01 ISSUE O

DATE 02 MAR 2005



SOLDERING FOOTPRINT*



SOD-723

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- Y14.5M, 1982.

 CONTROLLING DIMENSION: MILLIMETER.

 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF DACK MATERIAL. BASE MATERIAL.

	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.49	0.52	0.55	0.019	0.020	0.022	
b	0.25	0.28	0.32	0.0098	0.011	0.013	
С	0.08	0.12	0.15	0.0032	0.0047	0.0059	
D	0.95	1.00	1.05	0.037	0.039	0.041	
E	0.55	0.60	0.65	0.022	0.024	0.026	
HE	1.35	1.40	1.45	0.053	0.055	0.057	
L	0.15	0.20	0.25	0.006	0.0079	0.010	

GENERIC MARKING DIAGRAM*



XX = Specific Device Code Μ = Date Code

*This information is generic. Please refer to device data sheet for actual part marking.

Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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